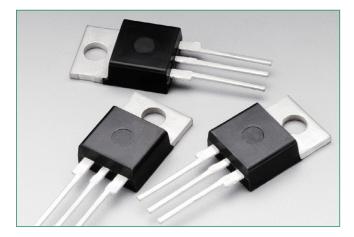
RoHS

Po

MAC15 Series TRIAC – 400V - 800V



Additional Information







Samples

Resources

Functional Diagram



Description

Designed primarily for full-wave ac control applications, such as solid-state relays, motor controls, heating controls and power supplies; or wherever full-wave silicon gate controlled solid-state devices are needed. Triac type thyristors switch from a blocking to a conducting state for either polarity of applied main terminal voltage with positive or negative gate triggering.

Features

- Blocking Voltage to 800 V
- All Diffused and Glass Passivated Junctions for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability

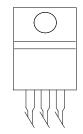
Pin Out





 Gate Triggering Guaranteed in Three Modes (MAC15 Series)

or Four Modes (MAC15A



Maximum Ratings (TJ = 25°C unless otherwise noted)

Rating		Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, $T_J = -40^{\circ}$ to 125°C)	MAC15A6G MAC15-8G, MAC15A8G MAC15-10G, MAC15A10G	V _{drm} , V _{rrm}	400 600 800	V
On-State RMS Current (Full Cycle Sine Wave, 50 to 60 H	lz, T _c = 80°C)	I _{T (RMS)}	15	А
Peak Non-Repetitive Surge Current (One Full Cycle Sine Preceded and Followed by Rated Current	Wave, 60 Hz, $T_c = 80^{\circ}C$)	I _{TSM}	150	А
Peak Gate Voltage (Pulse Width \leq 1.0 µsec; T _c = 90°C)	$V_{\rm GM}$	10	V	
Circuit Fusing Consideration (t = 8.3 ms)	l²t	93	A ² sec	
Peak Gate Power (Τ _c = 80°C, Pulse Width = 1.0 μs)	P _{GM}	20	W	
Peak Gate Current (Pulse Width \leq 1.0 µsec; T _c = 90°C)		I _{GM}	2.0	А
Average Gate Power (t = 8.3 ms, $T_c = 80^{\circ}C$)		P _{G (AV)}	0.5	W
Operating Junction Temperature Range	TJ	-40 to +125	°C	
Storage Temperature Range		T _{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the

Recommended Operating Conditions may affect device reliability.
1. V_{DBM} and V_{RBM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

Rating		Symbol	Value	Unit
Thermal Resistance,	Junction-to-Case (AC) Junction-to-Ambient	R _{øjc} R _{øja}	2.0 62.5	°C/W
Maximum Lead Temperature for Soldering Purpose	s, 1/8" from case for 10 seconds	TL	260	°C

Electrical Characteristics - OFF (TJ = 25°C unless otherwise noted ; Electricals apply in both directions)

Characteristic		Symbol	Min	Тур	Max	Unit
Peak Repetitive Blocking Current	T ₁ = 25°C	I _{DRM} ,	-	-	0.01	
$(V_{D} = V_{DRM} = V_{RRM}; \text{ Gate Open})$	T_ = 125°C	I	-	-	2.0	mA

Electrical Characteristics - ON (TJ = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic			Min	Тур	Max	Unit
Peak On–State Voltage (Note 2) ($I_{TM} = \pm 21$ A Peak)		V _{TM}	-	1.3	1.6	V
	MT2(+), G(+)		-	-	50	
Gate Trigger Current (Continuous dc)	MT2(+), G(-)		-	-	50	mA
$(V_{\rm p} = 12 \text{ V, } \text{R}_{\rm r} = 100 \Omega)$	MT2(-), G(-)	GT	-	-	50	ША
$(v_{\rm D} - 12, v, 11_{\rm L} - 100, 22)$	MT2(-), G(+)		-	-	75	
	MT2(+), G(+)		-	0.9	2	
Gate Trigger Voltage (Continuous dc) $(V_{p} = 12 V, R_{1} = 100 \Omega)$	MT2(+), G(-)	V	-	0.9	2	V
	MT2(-), G(-)	V _{gt}	-	1.1	2	V
$(v_{\rm D} - 12, v, 11_{\rm L} - 100, 22)$	MT2(-), G(+)		-	1.4	2.5	
	MT2(+), G(+)		0.2	-	-	
Gate Non–Trigger Voltage	MT2(+), G(-)	V	0.2	-	-	V
$(T_{J} = 110^{\circ}C)$ (V _D = 12 V, R ₁ = 100 Ω)	MT2(-), G(-)	V_{gD}	0.2	-	-	V
$(v_{\rm D} - 12, v, 11_{\rm L} - 100, 22)$	MT2(-), G(+)		0.2	-	-	
Holding Current ($V_{D} = 12 V_{dc'}$ Gate Open, Initiating Current = ±200 mA))		I _H	-	6.0	40	mA
Turn-On Time (VD = Rated VDRM, ITM = 17 A) (IGT = 120 mA, Rise Time = 0.1 μs, Pulse Width = 2 μs)		tgt	-	1.5	-	μs
 Indicates Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%. 						

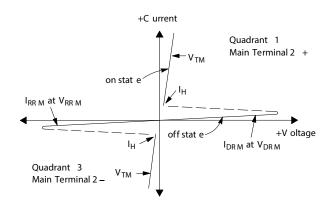


Dynamic Characteristics

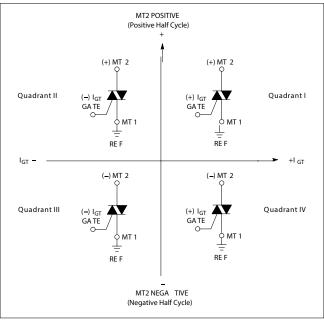
Characteristic	Symbol	Min	Тур	Max	Unit
Critical Rate of Rise of Commutation Voltage (V _D = Rated V _{DRM} , I _{TM} = 21 A, Commutating di/dt = 7.6 A/ms, Gate Unenergized, T _C = 80°C)	dV/dt	-	5.0	-	V/µs

Voltage Current Characteristic of SCR

Symbol	Parameter
V _{DRM}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1. With in-phase signals (using standard AC lines) quadrants I and III are used



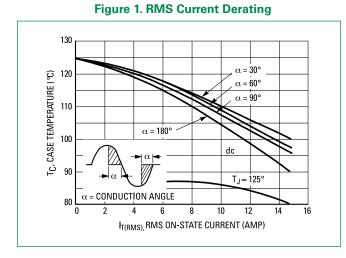


Figure 3. Typical Gate Trigger Voltage

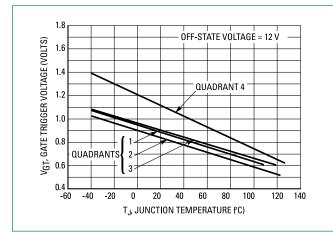


Figure 2. On-State Power Dissipation

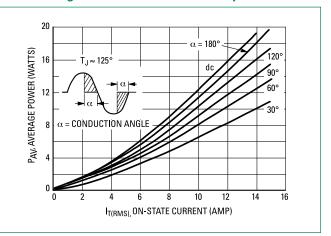
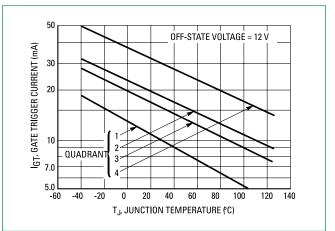


Figure 4. Typical Gate Trigger Current



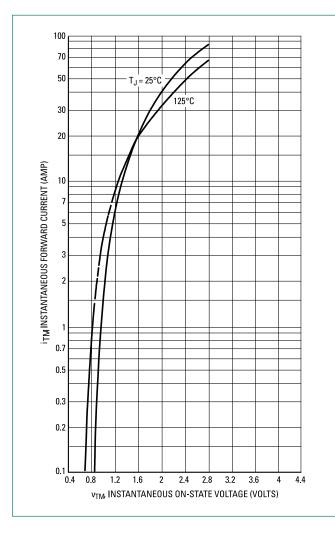


Figure 5. On–State Characteristics

Figure 6. Typical Holding Current

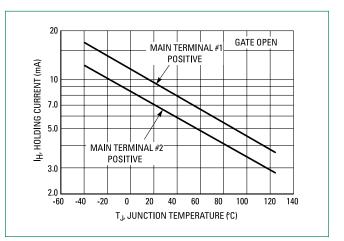
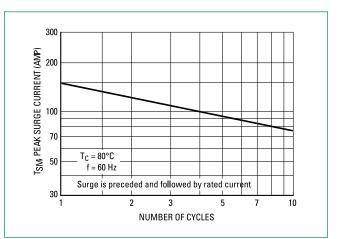
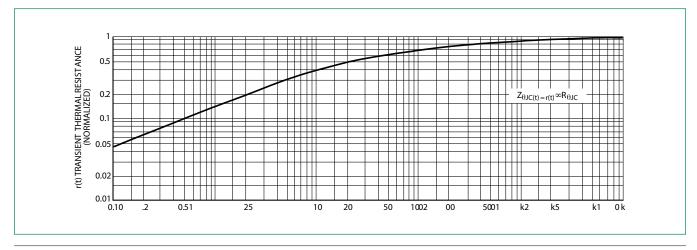


Figure 7. Maximum Non–Repetitive Surge Current

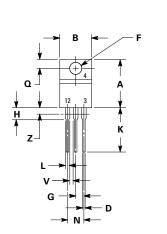


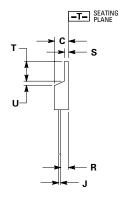




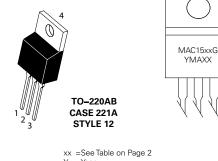
MAC15 Series TRIAC - 400V - 800V

Dimensions





Part Marking System



xx =See Table on Page 2 Y =Year M =Month A =Assembly Site XX =Lot Serial Code G =Pb-Free Package

Dim	Inches		Millim	neters
DIM	Min	Мах	Min	Max
Α	0.590	0.620	14.99	15.75
В	0.380	0.420	9.65	10.67
С	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.41	2.67
Н	0.110	0.130	2.79	3.30
J	0.018	0.024	0.46	0.61
К	0.540	0.575	13.72	14.61
L	0.060	0.075	1.52	1.91
Ν	0.195	0.205	4.95	5.21
٥	0.105	0.115	2.67	2.92
R	0.085	0.095	2.16	2.41
S	0.045	0.060	1.14	1.52
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	-	1.15	-
Z	-	0.080	-	2.04

Pin Assignment				
1	Main Terminal 1			
2	Main Terminal 2			
3	Gate			
4	Main Terminal 2			

Ordering Information

Device	Device Marking	Package	Shipping	
MAC15-8G	MAC15-8			
MAC15-10G	MAC1510	TO 00040		
MAC15A6G	MAC15A6	TO-220AB (Pb-Free)	1000 Units/Box	
MAC15A8G	MAC15A8			
MAC15A10G	MAC15A10			

1. Dimensioning and tolerancing per ansi y14.5m, 1982.

Controlling dimension: inch.
 Dimension z defines a zone where all body and lead irregularities are allowed.

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 2N6075A

 NTE5629
 NTE5688
 CTB08-400CW
 D31410
 BTA425Z-800BTQ
 KS100N12
 TOPT16-800C0,127
 OT408,135
 BT134-800E
 BT136D

 BTB16Q-600BW
 Z0409MF
 BTA04-600B
 BTA06-600BRG
 BTA06-800BWRG
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 MAC97A6,116
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 Z0109MN,135
 T825T-6I
 T1220T-6I
 NTE5638
 ACST1235-8FP

 BT136X-600E,127
 MAC4DLM-1G
 BT134-600D,127
 BTA08-600BW3G
 NTE56017
 NTE56018
 NTE56059
 NTE5608

 NTE5609
 NTE56020
 NTE56022
 NTE56022
 NTE56020
 NTE56022